

# Ultra low power video buffer/filter with power-down

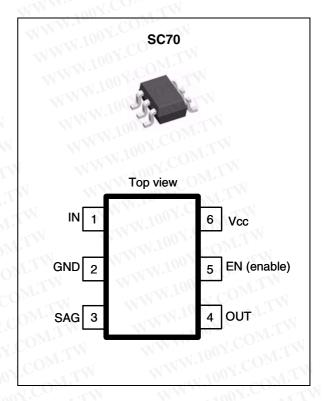
### **Features**

- Very low consumption: 1.7 mA
- Ultra low power-down mode: 4 nA typ., 500 nA max.
- Internal 6<sup>th</sup> order reconstruction filter
- Internal gain of 6 dB
- Rail-to-rail output buffer for 75 Ω video line
- Excellent video performance
  - Differential gain 0.5%
  - Differential phase 0.10°
  - Group delay of 10 ns
- SAG correction
- Bottom of video signal close to 0 V
- Tested with 2.5 V and 3.3 V single supply
- Data min. and max. are physically tested and guaranteed during production (consumption, gain, filtering, and other parameters are guaranteed)

# **Applications**

- Mobile phones
- Digital still camera
- Digital video camera
- Portable DVD players

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## **Description**

The TSH122 is a video buffer that uses a voltage feedback amplifier, with an internal gain of 6 dB, an output rail-to-rail, an internal input DC-shift and a SAG correction. A power-down function allows switching to a sleep mode with an ultra-low consumption.

The TSH122 features a 6th-order internal reconstruction filter to attenuate the parasitic frequency of 27 MHz from the clock of the video DAC.

The TSH122 operates from 2.25 to 5 V single power supplies and is tested at 2.5 V and 3.3 V.

The TSH122 is a single operator available in a tiny SC70 plastic package for space saving.

#### Absolute maximum ratings and operating conditions 1

**Absolute maximum ratings** 

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Supply voltage <sup>(1)</sup>	5.5	V
V <sub>in</sub>	Maximum input amplitude	0 to Vcc	٧
T <sub>stg</sub>	Storage temperature	-65 to +150	°C
T <sub>j</sub> W	Maximum junction temperature	150	°C
R <sub>thja</sub>	SC70 thermal resistance junction to ambient area	205	°C/W
R <sub>thjc</sub>	SC70 thermal resistance junction to case	172	°C/W
P <sub>max</sub>	Maximum power dissipation for Tj=150°C  T <sub>amb</sub> = +25°C  T <sub>amb</sub> = +85°C	609 317	mW
ESD	CDM: charged device model <sup>(2)</sup> HBM: human body model <sup>(3)</sup> MM: machine model <sup>(4)</sup>	1.5 1.5 300	kV kV V
VI-	Output short-circuit	(5)	N

- All voltage values, except differential voltage, are with respect to network terminal.
- WWW.100Y.G. Charged device model: all pins and the package are charged together to the specified voltage and then discharged directly to the ground through only one pin. This is done for all pins.
  - Human body model: a 100 pF capacitor is charged to the specified voltage, then discharged through a  $1.5~\mathrm{k}\Omega$  resistor between two pins of the device. This is done for all couples of connected pin combinations while the other pins are floating.
  - Machine model: a 200 pF capacitor is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor  $< 5 \Omega$ ). This is done for all couples of connected pin combinations while the other pins are floating
  - An output current limitation protects the circuit from transient currents. Short-circuits can cause excessive heating. Destructive dissipation can result from short-circuits on amplifiers.

**Operating conditions** Table 2.

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Power supply voltage	2.25 to 5 <sup>(1)</sup>	VCC
T <sub>oper</sub>	Operating free air temperature range	-40 to +85	Ov °C

1. Tested in full production at 0 V/2.5 V and 0 V/3.3 V single power supply. WWW.100Y.COM.TW WWW.100Y.

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#### **Electrical characteristics** 2

Table 3.  $V_{CC}$  = +2.5V, +3.3V,  $T_{amb}$  = 25°C (unless otherwise specified)

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DC norfor	MAN TO A COMP.	TW WAIN. TOOY.CL	T.1.7	N		
DC perfor	TIM WE CO	( D 4500	70	115	100	\/
V <sub>dc</sub>	Output DC level shift	$R_L = 150\Omega$	70	115	168	mV
l <sub>ib</sub> T	Input bias current	$V_{CC} = +3.3V$ $V_{CC} = +3.3V,$ $T_{min} \le T_{amb} \le T_{max}$	c-1.5	-0.87 -0.93		μΑ
COM	M MAN 100X	V <sub>in</sub> =0V to 1V DC, V <sub>CC</sub> =+2.5V	5.8	6	6.1	
Y.COM	Internal voltage gain	V <sub>in</sub> =0V to 1.4V DC, V <sub>CC</sub> =+3.3V	5.8	6	6.1	dB
ON.CO	internal voltage gain	$V_{CC}$ =3.3 $V$ $T_{min} \le T_{amb} \le T_{max}$	100X	5.96	TW	, db
PSRR	Power supply rejection ratio 20 log ( $\Delta V_{CC}/\Delta V_{out}$ )	ΔV <sub>CC</sub> =±100mV at 1kHz Vin=+0.5V DC	W.100	55	LTW	dB
I <sub>CC</sub>	Positive supply current	$V_{in}$ =0V, no load $V_{CC}$ =+3.3V $V_{CC}$ =+2.5V	MM·10	2 1.7	2.4 2.1	mA
VV.100	DC consumption	$V_{CC}$ =+3.3 $V$ $T_{min} \le T_{amb} \le T_{max}$	VAINA	2.4	$co_{M}$	mA
Dynamic	performance and output charac	cteristics	Wir	W.Ing.	V.CON	TW
BW	Filter bandwidth	Small signal $V_{CC}$ =+3.3V, $R_L$ = 150 $\Omega$ -3dB bandwidth -1dB bandwidth	5.4	9.5 7.2	00X.CO	MHz
	VW.100X.COM.TW	-1dB bandwidth $V_{CC} = +3.3V, \\ T_{min} \le T_{amb} \le T_{max}$		6.75	N 1007	COM.
FR	Q7 MHz rejection	Small signal $V_{CC}$ =+3.3V, $R_L$ =150 $\Omega$	36	47	W.10	dB
Гħ	27 MHz rejection	$V_{CC} = +3.3V$ , $T_{min} \le T_{amb} \le T_{max}$	LM.	46	WW.	dB
ΔG	Differential gain	$V_{CC}$ =+3.3V, $R_L$ =150 $\Omega$	TW	0.5	N	%
ΔΦ	Differential phase	$V_{CC}$ =+3.3V, $R_L$ =150 $\Omega$	17.7	0.1	VV TXV	N.100
Gd	Group delay	V <sub>CC</sub> =+3.3V, 10kHz-5MHz	MIT	6	NV TAX	ns
	High level output voltage	$V_{CC}$ =+3.3V, $R_L$ =150 $\Omega$ $V_{CC}$ =+2.5V, $R_L$ =150 $\Omega$	3.1 2.3	3.2 2.4	TV T	WV10

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 $V_{CC}$  = +2.5V, +3.3V,  $T_{amb}$  = 25°C (unless otherwise specified) (continued) Table 3.

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Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
$V_{OL}$	Low level output voltage	$R_L = 150\Omega$	WT	11	40	mV
I <sub>out</sub>	Output short circuit current	V <sub>CC</sub> =+2.5V	TW	75		mA
Noise and	distortion	M MMM. 100X.CO	om.TV	V		
eN	Total output noise	F = 100kHz, no load	M.T	51		nV/√Hz
HD	Harmonic distortion	$V_{CC}$ =+3.3V, $R_L$ = 150 $\Omega$ $V_{in}$ =1 $V_{p-p}$ , $F$ =1MHz	,coM	64		dBc
COMIT	wer-down	H2 H3	N.CON	61		
Enable/po Low level	wer-down on pin-5: TSH122 in power-down on pin-5: TSH122 enabled  Consumption in power-down	H3 W WWW.100	100X 100X 100X 00X 00X 00X		500	nA
Enable/po Low level High level	wer-down on pin-5: TSH122 in power-down on pin-5: TSH122 enabled	H3 W WWW.100	0	61	500	nA V
Enable/po Low level High level	wer-down on pin-5: TSH122 in power-down on pin-5: TSH122 enabled  Consumption in power-down mode	H3 W WWW.100	0 +0.7	61	. 1	
Enable/po Low level High level I <sub>sd</sub> V <sub>low</sub>	wer-down on pin-5: TSH122 in power-down on pin-5: TSH122 enabled  Consumption in power-down mode  Low-level threshold	H3 W WWW.100	111.2	61	+0.3	V

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Figure 1. Frequency response

Figure 2. Gain flatness

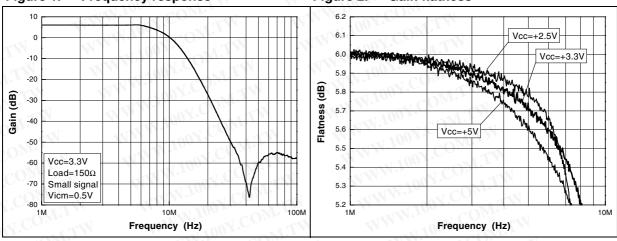


Figure 3. Input noise

Figure 4. Distortion

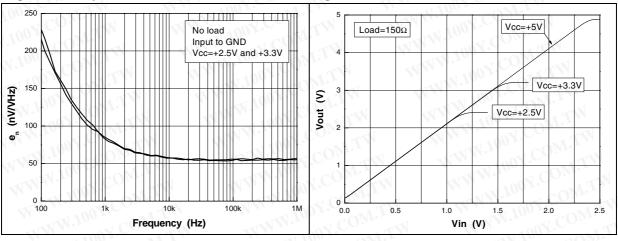
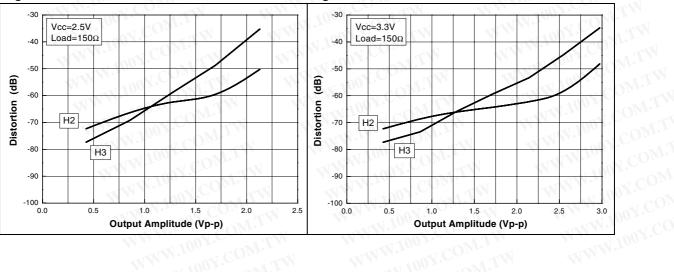


Figure 5. Distortion at Vcc=2.5 V

Figure 6. Distortion at Vcc=3.3 V

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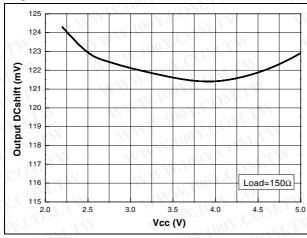


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Electrical characteristics TSH122

Figure 7. DCshift vs. Vcc

Figure 8. VOL vs. Vcc



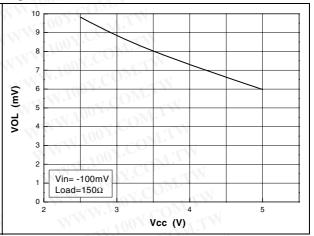
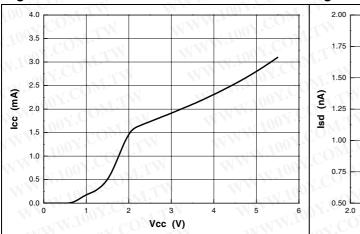


Figure 9. Icc vs. Vcc

Figure 10. Power down



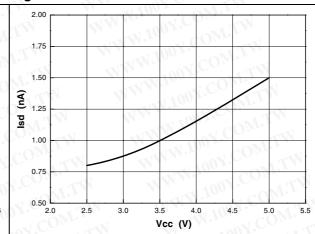
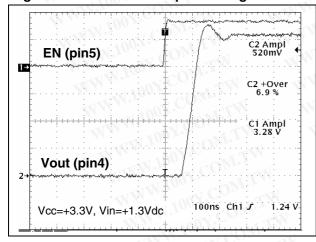
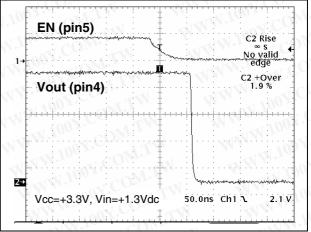


Figure 11. Switch-on output settling

Figure 12. Switch-off output settling



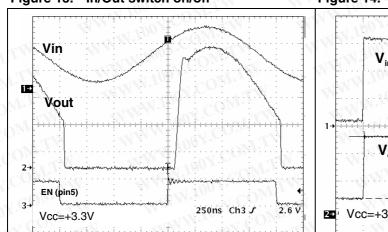
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Figure 13. In/Out switch on/off

Figure 14. Synchronization tip at 0 V



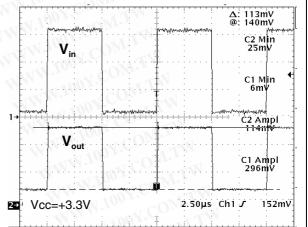
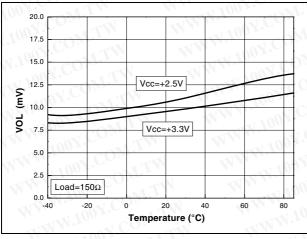


Figure 15. VOL vs. temperature

Figure 16. VOH vs. temperature



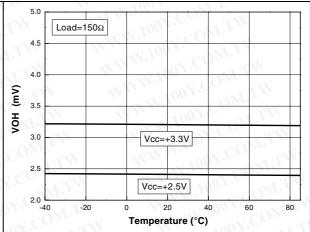
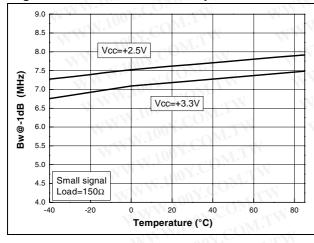
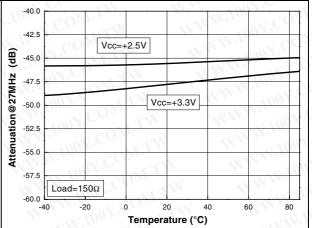


Figure 17. Bandwidth vs. temperature

Figure 18. Attenuation vs. temperature



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Figure 19. Icc vs. temperature

Figure 20. Gain vs. temperature

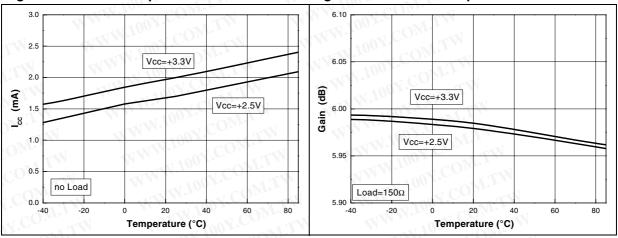
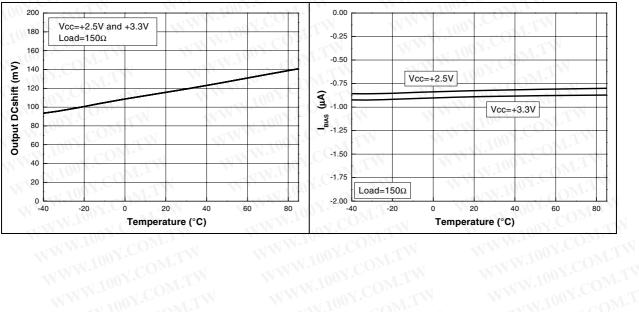


Figure 21. Output DC shift vs. temperature

Figure 22. Ibias vs. temperature

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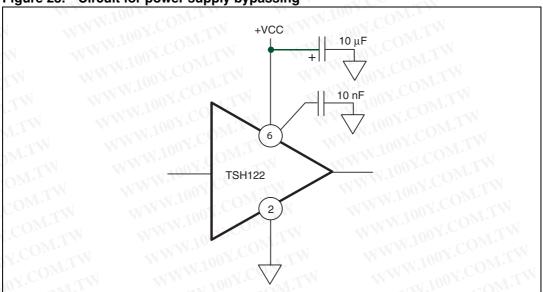
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# 3 Application information

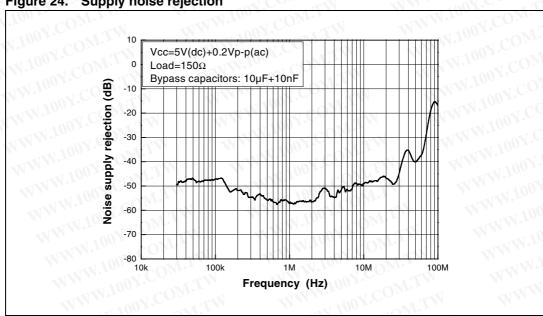
## 3.1 Power supply considerations

Correct power supply bypassing is very important for optimizing performance in high-frequency ranges. The bypass capacitors should be placed as close as possible to the IC pins to improve high-frequency bypassing. A capacitor greater than 10  $\mu$ F is necessary to minimize the distortion. For better quality bypassing, we recommend adding a 10 nF capacitor, also placed as close as possible to the IC pins.

Figure 23. Circuit for power supply bypassing







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## 3.2 Implementation considerations

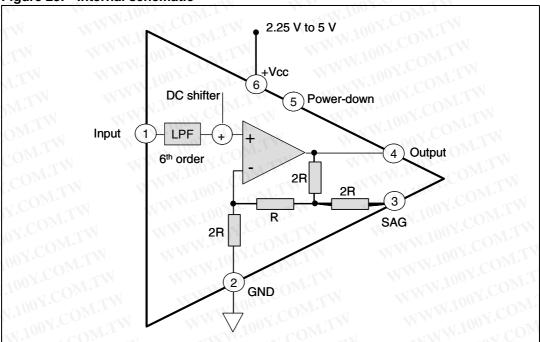
## 3.2.1 Input

The DC level shifter optimizes the position of the video signal with no clamping on the output rails.

### 3.2.2 Filter

A reconstruction filter is used to attenuate the DAC's sampling frequency because it generates a parasitic signal in the video spectrum (typically at 27 MHz in the case of standard video). This function is fulfilled while keeping a low group delay and a good gain flatness along the video band.

Figure 25. Internal schematic



### **3.2.3** Output

In an AC-coupling configuration, the SAG correction allows use of two small low-cost capacitors in place of one large capacitor (see *Figure 26*). The AC-coupling output reduces the power consumption by removing the DC component included in the signal.

Nevertheless, the output can be directly connected to the line without any capacitor. In this case, the OUT and SAG pins are connected together and the equivalent gain of the buffer remains at 6 dB (see *Figure 27*).

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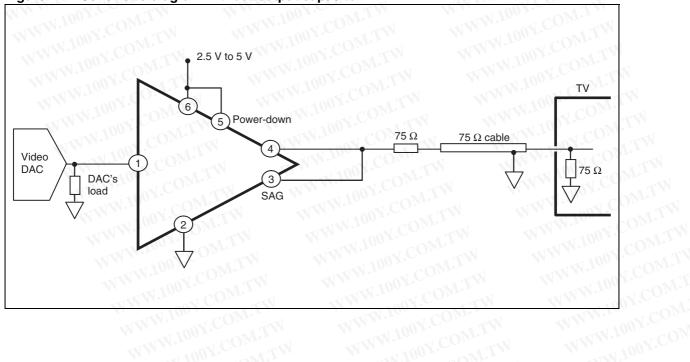
2.5 V to 5 V TV Power-down 75  $\Omega$  cable Video 75 Ω DAC DAC's load SAG 22 µF Equivalent to a single AC-coupling output with a big capacitor of 220 μF 220 µF 75 O 75  $\Omega$  cable 75 Ω

Schematic diagram with output capacitor



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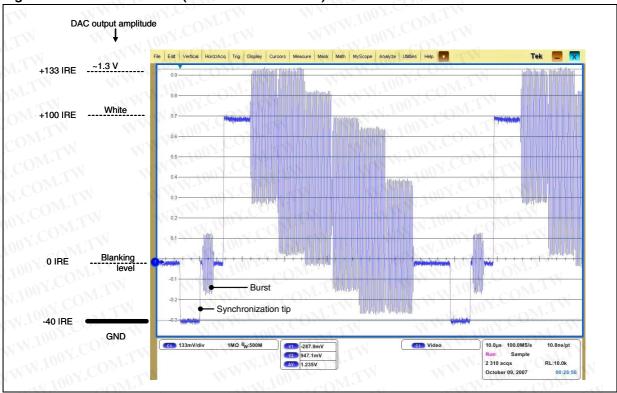
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#### 3.3 Using the TSH122 to drive a Cvbs signal

Figure 28. Details on Cvbs (NTSC color bar 100%)



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With its internal DC shift, the TSH122 can drive a video signal from the DAC output as low as 0 V (bottom of the synchronization tip at 0 V - see Figure 14).

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**TSH122 Package information** 

#### **Package information** 4

In order to meet environmental requirements, STMicroelectronics offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an STMicroelectronics trademark. ECOPACK specifications are available at: www.st.com.

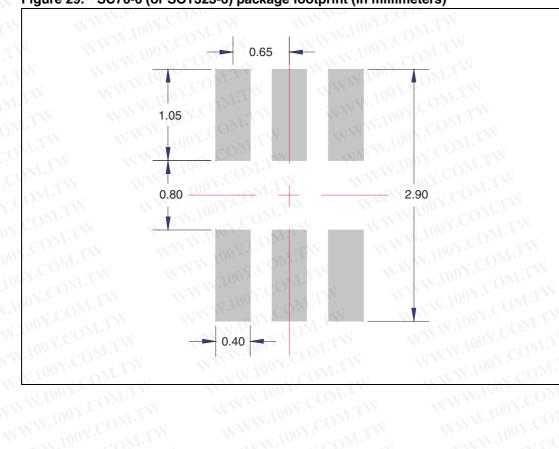


Figure 29. SC70-6 (or SOT323-6) package footprint (in millimeters)

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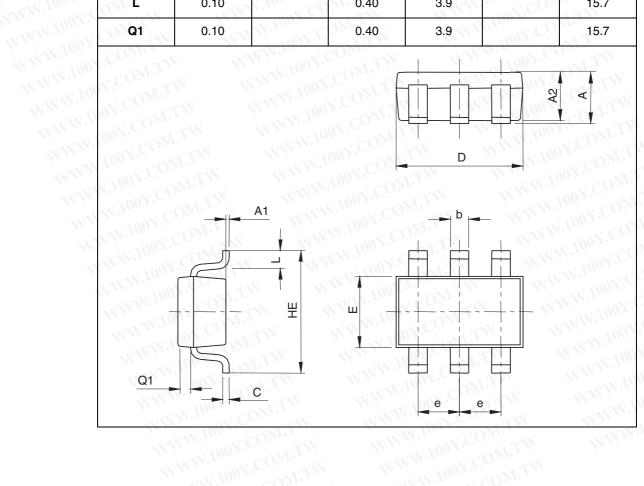
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Package information TSH122

Figure 30. SC70-6 (or SOT323-6) package mechanical data

MW.100			Dime	nsions		
Ref	Y.COM.	Millimeters	MM.100	COM	Mils	
WWW.IO	Min	Тур	Max	Min	Тур	Max
A	0.80	TW	1.10	31.5		43.3
A1	100 0 CO	M.I.A.	0.10	0.00	TW	3.9
A2	0.80	M. TW	1.00	31.5	WIIN	39.3
b WV	0.15	OMITW	0.30	5.9	WIW	11.8
c W	0.10	OMITH	0.18	3.9	TOM.TW	7.0
D	1.80	V.COM.TV	2.20	70.8	COMIT	86.6
E	1.15	oy.COM.	1.35	45.2	I.COM.	43.1
e	MMM	0.65	TW	WWW.10	25.6	N
HE	1.8	1001.CO	2.4	70.8	OOY.COM	94.5
OM.EW	0.10	N.100X.CO	0.40	3.9	TOO Y. CON	15.7
Q1	0.10	M.1003.	0.40	3.9	(Ton 2	15.7



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# WWW.100Y.COM.TW Ordering information 5

Order codes

e 4. Ord	er codes	100	OM.1	
Part number	Temperature range	Package	Packaging	Marking
TSH122ICT	-40°C to +85°C	SC70	Tape & reel	K31

# WWW.100X.COM.TW W.100Y.COM.T WWW.100X 6 M.TW **Revision history** WWW.100Y.C WWW.100Y.COM.TV

Table 5. **Document revision history** 

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	Changes
04-Aug-2008 1 Initial release.	MMM: TOWN: COLVE

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